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AUTHOR'S RELEVANT PUBLICATIONS

Journals:

1. V. Devarakonda, A.D.D. Dwivedi, A. Pandey, and P. Chakrabarti, "Performance analysisof $N^{+} - CdTe/\, n^{0} - Hg_{0.824675}Cd_{0.175325}Te\ /p^{+} - Hg_{0.824675}Cd_{0.175325}Te$ n-i-p photodetector operating at 30 µm wavelength for terahertz applications," *Optical and Quantum Electronics*, vol. 52, no. 7, Jul. 2020, doi: 10.1007/s11082-020-02450-1.

2. V. Devarakonda, A. Pandey, and P. Chakrabarti, "Enhanced optoelectronic properties of a mercury cadmium telluride based double heterojunction photodetector for terahertz applications," *Optik*, vol. 247, Dec. 2021, doi: 10.1016/j.ijleo.2021.167947.

3. V. Devarakonda, A. Pandey, and P. Chakrabarti, "A Proposed Graphene-Gated Semiconductor Terahertz Detector" submitted in *Optik.* (Under Review)